

## Type CRGP Series

### Key Features

Small size and light weight

Suitable for both wave and reflow soldering techniques

Supplied on tape

Pulse Rated

7 different package sizes

Terminal finish matte Sn over Ni

AEC-Q200

Compliant

Moisture sensitivity level - MSL1



TE Connectivity is pleased to introduce this SMD Pulse withstand thick film Chip resistor, suitable for auto placement in volume and for most applications. Available in five different packages and supplied on tape and reel for automatic insertion processes. Standard values – E24 Series and now AEC-Q200 Qualified

**Note:** SMD (Surface mount devices) resistors and inductors should be kept in their original packaging to protect them from ESD (Electrostatic Discharge). The full reels can be broken into smaller quantities, without exposing them to ESD, as long as the components are still in the plastic or paper tape. These resistors and inductors should not be removed from the plastic or paper tape unless they are in an ESD protected environment.

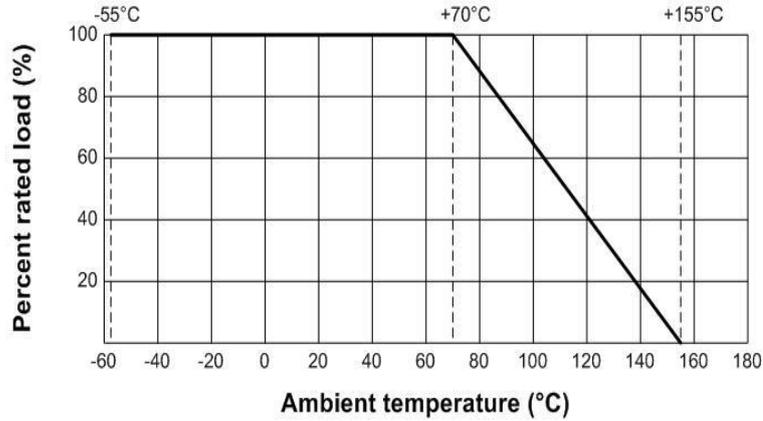
### Characteristics – Electrical

Type	CRGP0402	CRGP0603	CRGP0805	CRGP1206
Power Rating @ 70°C	0.125W	0.25W	0.33W	0.5W
Max. Working Voltage	50V	50V	150V	200V
Max. Overload Voltage	100V	100V	300V	400V
Dielectric Withstand	100V	300V	500V	500V
Temperature Range	-55°C ~ +155°C			
Ambient Temperature	70°C			

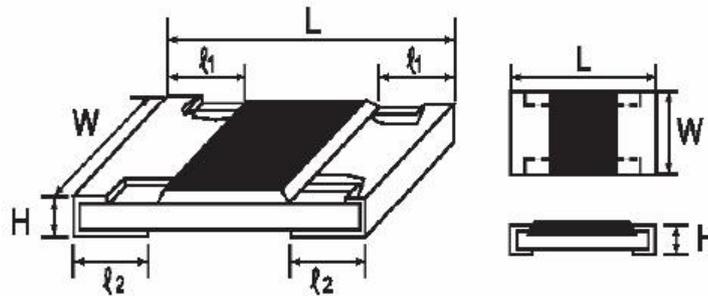
Type	CRGP1210	CRGP2010	CRGP2512
Power Rating @ 70°C	0.75W	1.25W	2W
Max. Working Voltage	200V	400V	500V
Max. Overload Voltage	500V	800V	1000V
Dielectric Withstand	500V	500V	500V
Temperature Range	-55°C ~ +155°C		
Ambient Temperature	70°C		

### Power derating curve

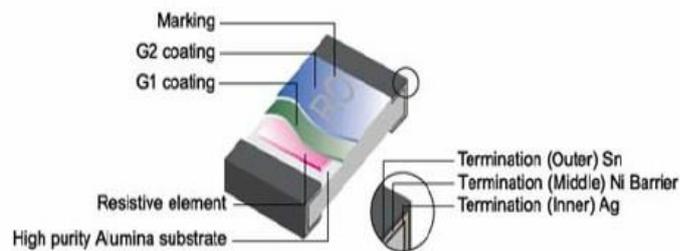
Power rating based on continuous load operation in ambient temperature of 70°C. For resistors operated in ambient temperatures above 70°C, power rating must be derated in accordance with this curve.



### Dimensions:



Type	Dimension (mm)				
	L	W	H	l1	l2
CRGP0402	1.10±0.10	0.50±0.05	0.35±0.05	0.20±0.10	0.25±0.10
CRGP0603	1.60±0.10	0.80±0.10	0.45±0.10	0.30±0.20	0.30±0.20
CRGP0805	2.00±0.15	1.25+0.15 -0.10	0.55±0.10	0.40±0.20	0.40±0.20
CRGP1206	3.10±0.15	1.55+0.15 -0.10	0.55±0.10	0.45±0.20	0.45±0.20
CRGP1210	3.10±0.10	2.60±0.20	0.55±0.10	0.55±0.25	0.50±0.20
CRGP2010	5.00±0.10	2.50±0.20	0.55±0.10	0.60±0.25	0.50±0.20
CRGP2512	6.35±0.10	3.20±0.20	0.55±0.10	0.60±0.25	0.50±0.20

**Construction:****Power Rating and Resistance Range:**

Type	Power Rating @ 70°C	Tolerance	Resistance Range	Standard Series
CRGP0402	0.125W	±1%	1R0 – 10M	E24 E96 by negotiation
		±5%		
CRGP0603	0.25W	±1%	1R0 – 10M	E24 E96 by negotiation
		±5%		
CRGP0805	0.33W	±1%	1R0 – 10M	E24 E96 by negotiation
		±5%		
CRGP1206	0.5W	±1%	1R0 – 10M	E24 E96 by negotiation
		±5%		
CRGP1210	0.75W	±1%	1R0 – 10M	E24 E96 by negotiation
		±5%		
CRGP2010	1.25W	±1%	1R0 – 10M	E24 E96 by negotiation
		±5%		
CRGP2512	2W	±1%	1R0 – 10M	E24 E96 by negotiation
		±5%		

**Marking:**

E24 series 0603 – 2512 3 Digits – first two digits denote significant figures of resistance and third digit denotes number of zeros thereafter. EG

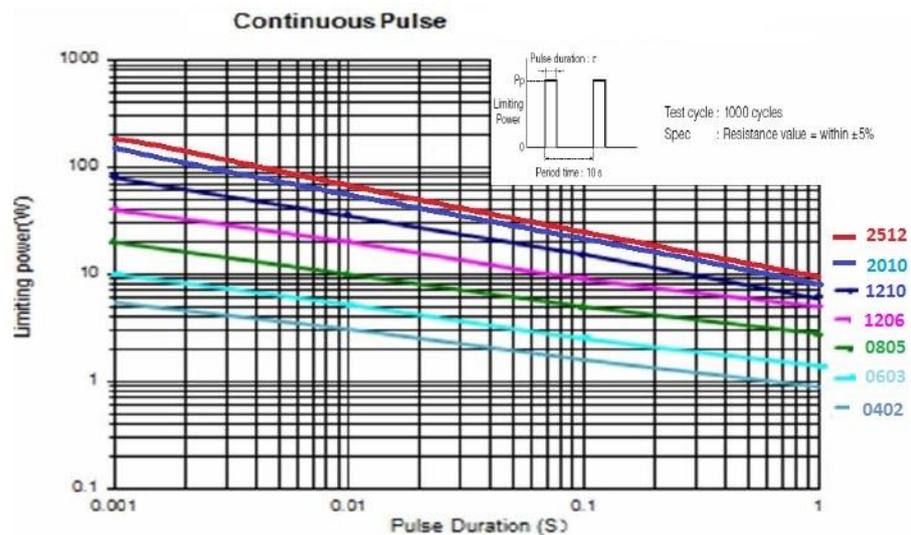
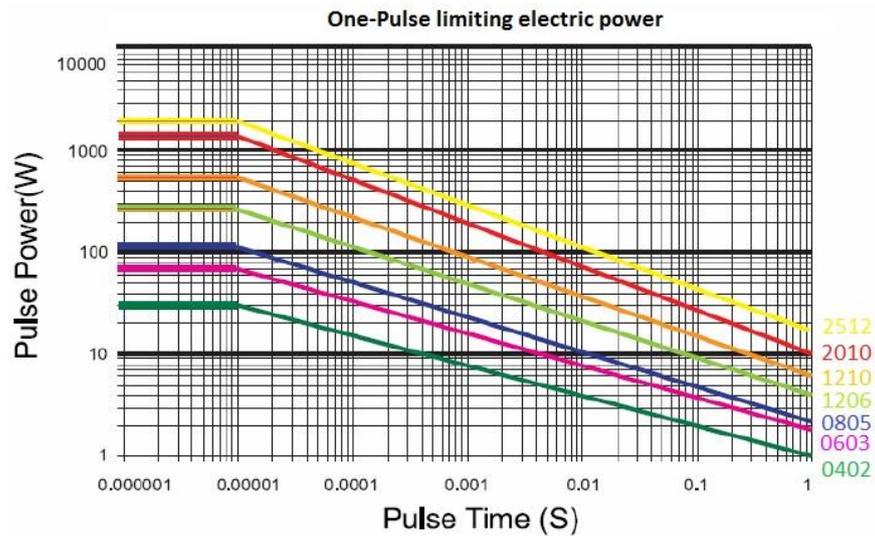
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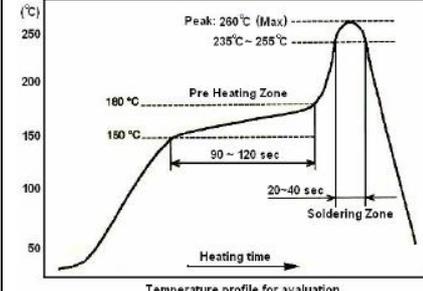
### Pulse withstand capacity

The single impulse graph is the result of 50 impulses of rectangular shape applied at one-minute intervals. The limit of acceptance was a shift in resistance of less than 1% from the initial value. The power applied was subject to the restrictions of the maximum permissible impulse voltage graph shown.



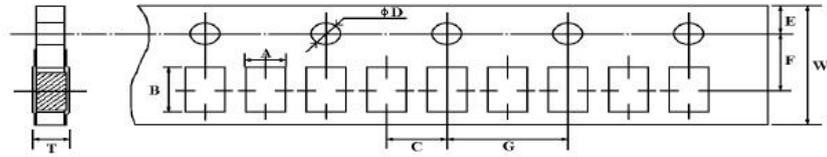
**Performance Specification:**

Characteristic	Limits	Test Methods (AEC-Q200)
Operational life	±5%, ±10%, ±20%: ±(3%+0.1Ω)Max.	125°C, at35% of operating power, 1000H(1.5 hours “ON”, 0.5 hour “OFF”). (MIL-STD-202)
Temperature Coefficient	1Ω~10Ω : ± 400 PPM/°C 10.1Ω~10MΩ : ± 100 PPM/°C	Natural resistance change per temp. degree centigrade R1-R2 ----- x10 <sup>6</sup> (PPM/°C) R1(t2-t1) R1 resistance value at room temperature (t1) R2 Resistance value at room temperature +100°C (t2)
External Visual	No Mechanical Damage	Electrical test not required. Inspect device construction, marking and workmanship (MIL-STD-883 Method 2009)
Physical Dimensions	Reference 2.0 Dimension Standards	Verify physical dimensions to the applicable device detail specification. Note: User(s) and Suppliers spec. Electrical test not required. (JESD22 MH Method JB-100)
Resistance to Solvent	Marking Unsmearred	Note: Add Aqueous wash chemical – OKEM Clean or equivalent. Do not use banned solvents. ( MIL-STD-202 Method 215)
Terminal Strength	Not Broken	Force of 1.8kg for 60 seconds. (JIS-C-6429)
Terminal Bending	± (1.0% ±0.05Ω) Max.	Twist of Test Board : Y/X = 5/90 mm for 10 seconds (Sub-clause 4.33)
High Temperature Exposure (Storage)	±(1%+0.1Ω)max	1000hrs. @T=155°C.Unpowered. Measurement at 24±2 hours after test conclusion. (MIL-STD-202 Method 108)
Temperature Cycling	Resistance change rate is ±5%, ±10%, ±20%: ± (1.0%+0.1Ω) Max.	1000 Cycles (-55°C to +155°C). Measurement at 24±2 hours after test conclusion. (JESD22 Method JA-104)
Solderability	95% coverage Min.	Test temperature of solder : 245 ± 3 °C Dwell time in solder : 2 ~ 3 seconds (Sub-clause 4.17) For both leaded & SMD. Electrical test not required. 95% coverage Min. Magnification 50X. Conditions: ( J-STD-002)
Soldering Heat	Resistance change rate is ±(1.0%+0.05Ω) Max.	Dip the resistor into a solder bath having a temperature of 260°C±3°C and hold it for 10±1 seconds (Sub-clause 4.18)
Insulation Resistance	1,000MΩ or more	Apply 500V DC between protective coating and termination for 1 min, then measure (Sub-clause 5.6)

Characteristic	Limits	Test Methods (AEC-Q200)
Solder Temp. Reference	Electrical characteristics shall be satisfied without distinct deformation in appearance. (95% coverage Min.)	Wave soldering condition: (2 cycles Max.) Pre-heat : 100 ~ 120 °C, 30 ± 5 sec. Suggestion solder temp.: 235 ~ 255 °C, 10 seconds max. Peak temp.: 260 °C Reflow soldering condition: (2 cycles Max.) Pre-heat : 150 ~ 180 °C, 90 ~ 120 sec. Suggestion solder temp.: 235 ~ 255 °C, 20 ~ 40 sec. Peak temp.: 260 °C  Hand Soldering 300°C 5 seconds
Short term overload	Resistance change rate is ±5% : ±(2.0% ±0.1Ω) Max. ±1% : ±(1.0% ±0.1Ω) Max.	Permanent resistance change after the application of a potential of 2.5 times RCWV for 5 seconds Sub-clause 4.13
Dielectric Withstand Voltage	No evidence of flashover, mechanical damage, arcing or insulation breakdown.	Apply 500V AC between protective coating and termination for 1 minute (Sub-clause 4.7)
Humidity	Resistance change rate is: ± (3.0% + 0.1Ω) Max.	Temporary resistance change after 240 hours exposure in a humidity test chamber controlled at 40±2°C and 90-95% relative humidity (Sub-clause 4.24)
Load Life In Humidity	Resistance change rate is: ±5% : ±(3.0% ±0.1Ω) Max. ±1% : ±(1.0% ±0.1Ω) Max.	Resistance change after 1,000 hours (1.5 hours "on", 0.5 hour "off") at RCWV in a humidity chamber controlled at 40°C ± 2°C and 90 to 95 % relative humidity. (Sub-clause 4.24.2.1)
Load Life	Resistance change rate is: ±5% : ±(3.0% ±0.1Ω) Max. ±1% : ±(1.0% ±0.1Ω) Max.	Permanent resistance change after 1,000 hours operating at RCWV, with duty cycle of (1.5 hours "on", 0.5 hour "off") at 70°C ± 2°C ambient (Sub-clause 4.25.1)

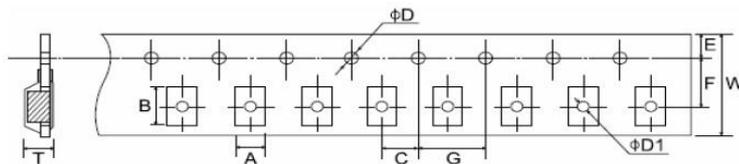
### Packaging Specification

#### Paper Taping



Type	A ±	B ±	C ±	ØD +0.1 -0	E ±	F ±	G ±	W ±	T ±
0402	0.65	1.15	2.0	1.5	1.75	3.5	4.0	8.0	0.45
0603	1.10	1.90	2.0	1.5	1.75	3.5	4.0	8.0	0.67
0805	1.65	2.40	2.0	1.5	1.75	3.5	4.0	8.0	0.81
1206	2.00	3.60	2.0	1.5	1.75	3.5	4.0	8.0	0.81
1210	2.80	3.50	2.0	1.5	1.75	3.5	4.0	8.0	0.75

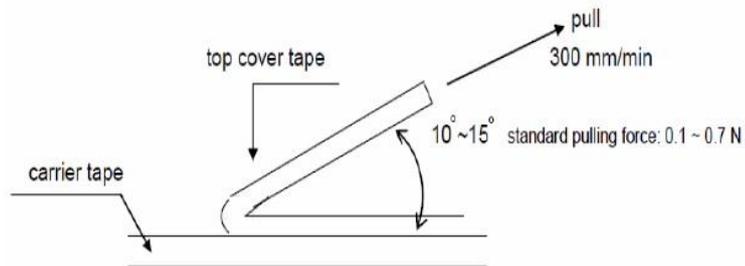
#### Embossed Taping



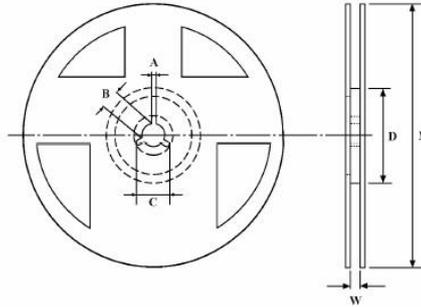
Type	A ±	B ±	C ±	ØD +0.1 -0	ØD1 +0.1 -0	E ±	F ±	G ±	W ±	T ±
2010	2.90	5.60	2.0	1.5	1.5	1.75	5.5	4.0	12.0	1.0
2512	3.50	6.70	2.0	1.5	1.5	1.75	5.5	4.0	12.0	1.0

Peeling strength of cover tape:

Test condition: 0.1 to 0.7 N at a peel off speed of 300mm / min.



Reel Dimensions (mm):



Type	Tape	Reel Qty	A ± 0.5	B ± 0.5	C ± 0.5	D ± 1	M ± 2	W ± 1
0402	Paper	10,000	2	13	21	60	178	10
0603	Paper	5,000	2	13	21	60	178	10
0805	Paper	5,000	2	13	21	60	178	10
1206	Paper	5,000	2	13	21	60	178	10
1210	Paper	5,000	2	13	21	60	178	10
2010	Embossed	4,000	2	13	21	60	178	13.8
2512	Embossed	4,000	2	13	21	60	178	13.8

#### Environment Related Substance

This product complies to EU RoHS directive, EU PAHs directive, EU PFOS directive and Halogen free.

#### Ozone layer depleting substances.

Ozone depleting substances are not used in our manufacturing process of this product.

This product is not manufactured using Chloro fluorocarbons (CFCs), Hydrochlorofluorocarbons (HCFCs), Hydrobromofluorocarbons (HBFCs) or other ozone depleting substances in any phase of the manufacturing process.

#### Storage Condition

The performance of these products, including the solderability, is guaranteed for a year from the date of arrival at your company, provided that they remain packed as they were when delivered and stored at a temperature of  $25^{\circ}\text{C} \pm 10^{\circ}\text{C}$  and a relative humidity of  $60\%\text{RH} \pm 10\%\text{RH}$ , chemical and dust free atmosphere

Even within the above guarantee periods, do not store these products in the following conditions otherwise, their electrical performance and/or solderability may be deteriorated, and the packaging materials (e.g. taping materials) may be deformed or deteriorated, resulting in mounting failures.

1. In salty air or in air with a high concentration of corrosive gas, such as  $\text{Cl}_2$ ,  $\text{H}_2\text{S}$ ,  $\text{NH}_3$ ,  $\text{SO}_2$ , or  $\text{NO}_2$
2. In direct sunlight

**Solder Profile**

Wave soldering condition: (2 cycles Max.)

Pre-heat : 100 ~ 120 °C, 30 ± 5 sec.

Suggestion solder temp.: 235 ~ 255 °C, 10 seconds

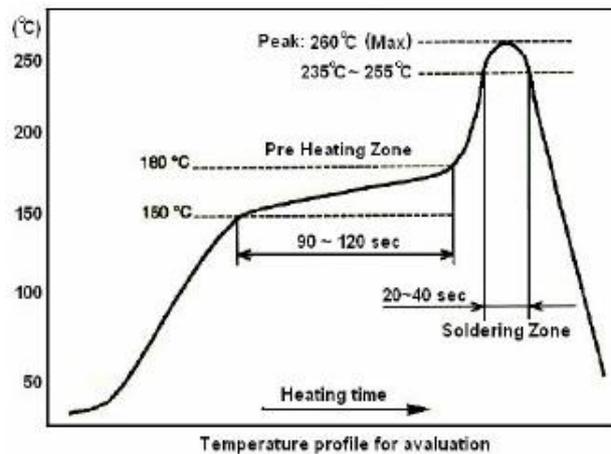
Peak temp.: 260 °C

Reflow soldering condition: (2 cycles Max.)

Pre-heat : 150 ~ 180 °C, 90 ~ 120 sec.

Suggestion solder temp.: 235 ~ 255 °C, 20 ~ 40 seconds

Peak temp.: 260 °C



Hand Soldering condition: The Soldering iron tip should be less than 300°C and maximum contact time should be 5 seconds

**How To Order**

CRGP	0603	J	10K
Common Part	Size	Tolerance	Resistance Value
CRGP – Pulse Withstand Thick Film Chip Resistor	0402	F - ±1% J - ±5%	1 ohm (1Ω) 1R0
	0603		1K ohm (1000Ω) 1K0
	0805		100K ohm (100000Ω) 100K
	1206		
	1210		
	2010		
	2512		1M ohm (1000000Ω) 1M0